

# iscN-Channel MOSFET Transistor

# **TK70J04K3Z**

#### • FEATURES

- Low drain-source on-resistance:
  R<sub>DS</sub>(ON) = 4.1mΩ (MAX)
- Enhancement mode:
  Vth = 3 to 4V (VDS = 10 V, ID=1.0mA)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



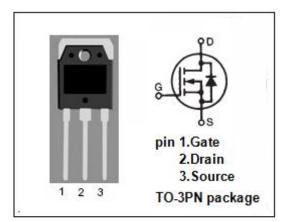
· Switching Voltage Regulators

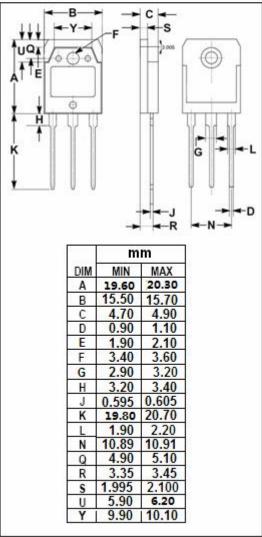
### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage 40			
V <sub>GS</sub>	Gate-Source Voltage ±20			
I <sub>D</sub>	Drain Current-Continuous 70			
I <sub>DM</sub>	Drain Current-Single Pulsed 280		Α	
$P_D$	Total Dissipation @T <sub>C</sub> =25°C 125		W	
Tj	Max. Operating Junction Temperature	nperature 150		
T <sub>stg</sub>	Storage Temperature -55~150		$^{\circ}$	

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	1.2	°C/W







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#### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 10mA	40			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> =1.0mA	3		4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =35A			4.1	mΩ
lgss	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0V			±1	μ <b>А</b>
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =40V; V <sub>GS</sub> = 0V			10	μ <b>А</b>
V <sub>SDF</sub>	Diode forward voltage	I <sub>DR</sub> =70A, V <sub>GS</sub> = 0 V			1.2	V



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